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Kind regards,

Team Nexperia



# Ultra low capacitance bidirectional ESD protection diode Rev. 1— 2 September 2013 Product data

Product data sheet

#### 1. **General description**

Ultra low capacitance bidirectional ElectroStatic Discharge (ESD) protection diode in a DFN1006-2 (SOD882) leadless ultra small Surface-Mounted Device (SMD) plastic package designed to protect one signal line from the damage caused by ESD and other transients.

#### 2. Features and benefits

- Ultra low diode capacitance C<sub>d</sub> = 0.35 pF
- High reverse standoff voltage V<sub>RWM</sub> = 18 V
- Very small voltage dependency of the capacitance
- ESD protection up to ±10 kV according to IEC 61000-4-2, level 4

#### **Applications** 3.

- NFC antenna protection
- · Protection of high-speed data lines

#### Quick reference data 4.

Table 1.	Quick reference da	ta				
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
C <sub>d</sub>	diode capacitance	$f = 1 \text{ MHz}; V_R = 0 \text{ V}$	0.28	0.35	0.5	pF
$V_{RWM}$	reverse standoff voltage		-	-	18	V

#### **Pinning information** 5.

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K1	cathode (diode 1)		
2	K2	cathode (diode 2)	1 2	1 2 sym045
			Transparent top view	
			DFN1006-2 (SOD882)	



#### Ultra low capacitance bidirectional ESD protection diode

## 6. Ordering information

g information		
Package		
Name	Description	Version
DFN1006-2	leadless ultra small plastic package; 2 terminals	SOD882
	Package Name	Package   Name Description

### 7. Marking

#### Table 4.Marking codes

Type number	Marking code
PESD18VF1BL	WM

### 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

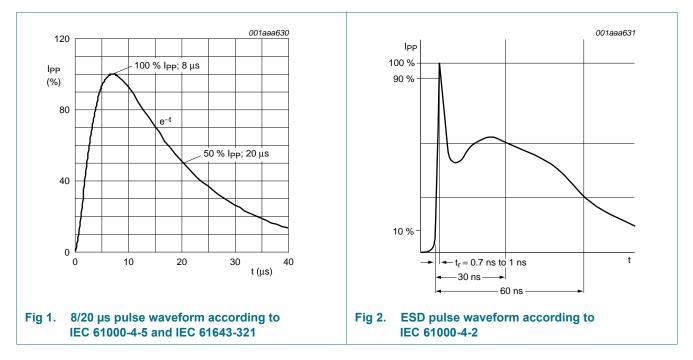
Symbol	Parameter	Conditions		Min	Мах	Unit
I <sub>PPM</sub>	peak pulse current	t <sub>p</sub> = 8/20 μs; IEC 61000-4-5; IEC 61643-321	<u>[1]</u>	-	1	А
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
ESD maximu	m ratings					
V <sub>ESD</sub>	electrostatic discharge voltage	IEC 61000-4-2; contact discharge	<u>[1][2]</u>	-	10	kV
		IEC 61000-4-2; air discharge	<u>[1][2]</u>	-	15	kV
		MIL-STD-883; human body model; HBM	<u>[1]</u>	-	10	kV
		machine model; MM	<u>[1]</u>	-	400	V

[1] Measured from pin 1 to pin 2.

[2] Device stressed with ten non-repetitive ESD pulses.

# PESD18VF1BL

Ultra low capacitance bidirectional ESD protection diode



### 9. Characteristics

Table 6.	Characteristics
Table 0.	Characteristics

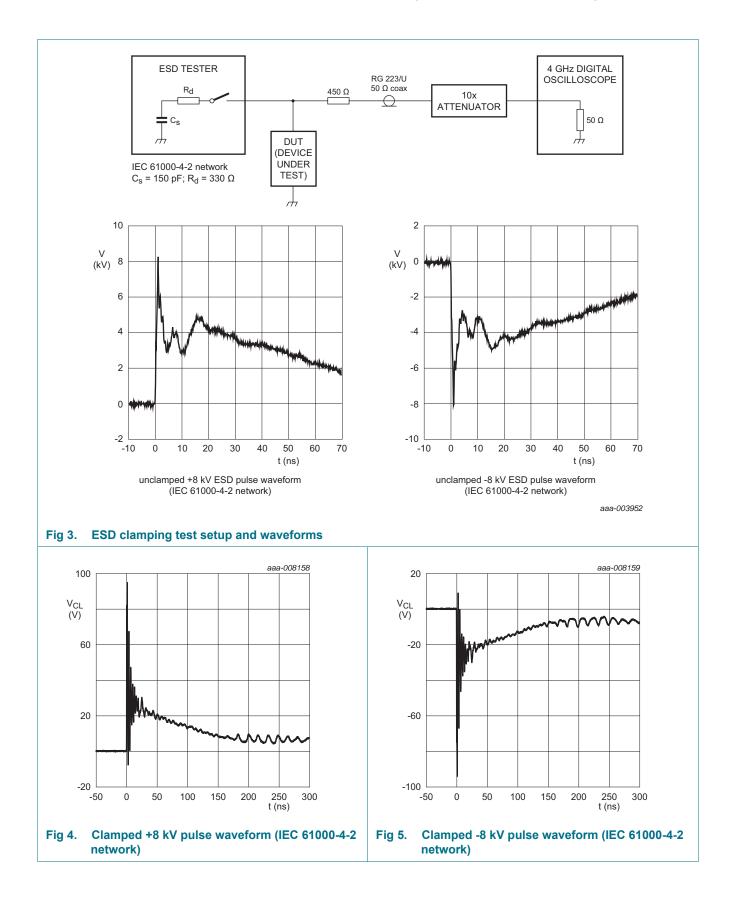
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>RWM</sub>	reverse standoff voltage			-	-	18	V
I <sub>RM</sub>	reverse leakage current	V <sub>R</sub> = 18 V		-	1	30	nA
V <sub>CL</sub>	clamping voltage	I <sub>PP</sub> = 1 A; t <sub>p</sub> = 8/20 μs; IEC 61000-4-5; IEC 61643-321	<u>[1]</u>	-	-	17	V
V <sub>BR</sub>	breakdown voltage	I <sub>R</sub> = 10 mA		19	22	24	V
C <sub>d</sub>	diode capacitance	$f = 1 MHz; V_R = 0 V$		0.28	0.35	0.5	pF
R <sub>dyn</sub>	dynamic resistance	I <sub>R</sub> = 10 A	[2]	-	0.8	-	Ω

[1] Measured from pin 1 to pin 2.

[2] Non-repetitive current pulse, Transmission Line Pulse (TLP) t<sub>p</sub> = 100 ns; square pulse; ANSI / ESD STM5.1-2008.

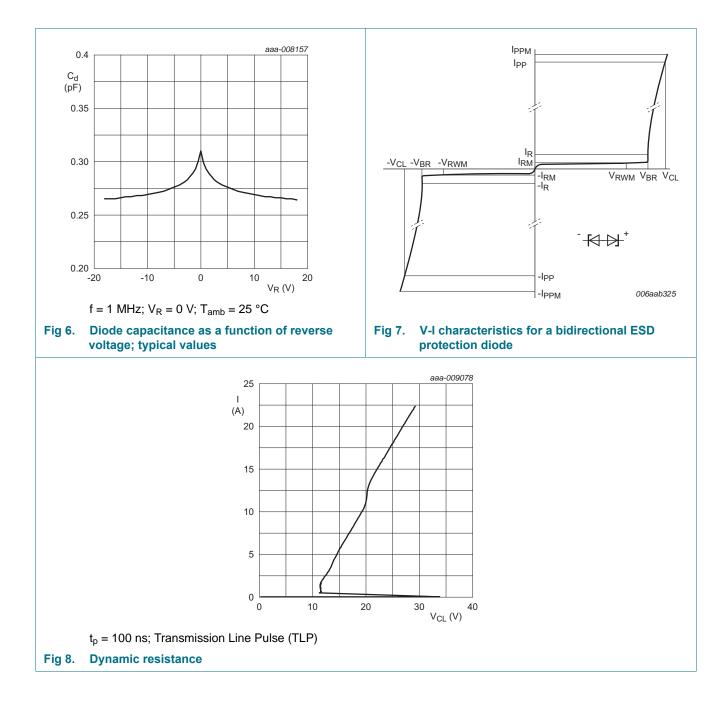
# PESD18VF1BL

#### Ultra low capacitance bidirectional ESD protection diode



# PESD18VF1BL

#### Ultra low capacitance bidirectional ESD protection diode

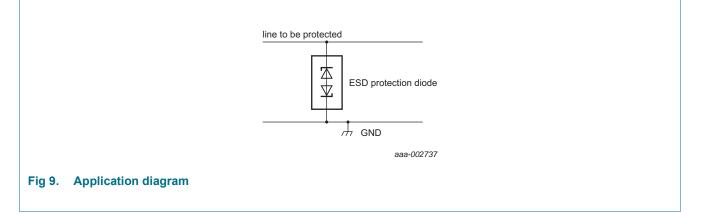


# PESD18VF1BL

Ultra low capacitance bidirectional ESD protection diode

### **10. Application information**

The device is designed for the protection of one bidirectional data line from surge pulses and ESD damage. The device is suitable on lines where the signal polarities are both positive and negative with respect to ground.



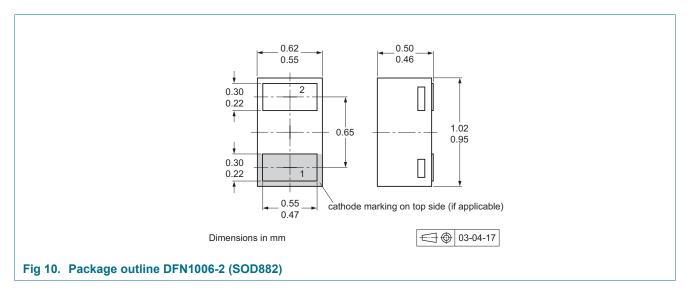
#### Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

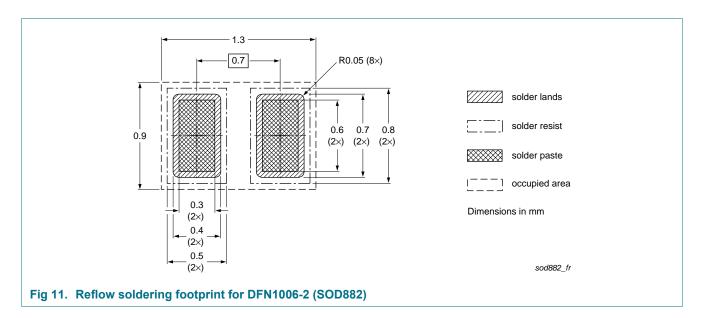
- 1. Place the device as close to the input terminal or connector as possible.
- 2. Minimize the path length between the device and the protected line.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- Use ground planes whenever possible. For multilayer PCBs, use ground vias.

Ultra low capacitance bidirectional ESD protection diode

# 11. Package outline



# 12. Soldering



### Ultra low capacitance bidirectional ESD protection diode

# **13. Revision history**

Table 7. Revision h	7. Revision history				
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes	
PESD18VF1BL v.1	20130902	Product data sheet	-	-	

### 14. Legal information

#### 14.1 Data sheet status

Document status <sup>[1]</sup> [2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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PESD18VF1BL

#### Ultra low capacitance bidirectional ESD protection diode

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# **PESD18VF1BL**

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### 16. Contents

1	General description
2	Features and benefits1
3	Applications1
4	Quick reference data1
5	Pinning information1
6	Ordering information
7	Marking
8	Limiting values2
9	Characteristics3
10	Application information
11	Package outline7
12	Soldering7
13	Revision history8
14	Legal information9
14.1	Data sheet status9
14.2	Definitions9
14.3	Disclaimers
14.4	Trademarks10
15	Contact information10

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